RM2C

1 Scope

The present specifications shall apply to Sanken silicon diode, RM2C.

2 Outline

Туре	Silicon Rectifier Diode (Mesa type)				
Structure	Resin Molded Flammability: UL94V-0 (Equivalent)				
Applications	Commercial Frequency Rectification, etc				

3 Absolute maximum ratings

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	No.	Item	Symbol	Unit	Rating	Conditions	
	1	Transient Peak Reverse Voltage	V _{RSM}	V	1050		
	2	Peak Reverse Voltage	V _{RM}	V	1000		
	3	Average Forward Current	I _{F(AV)}	А	1.2	Refer to derating curve in Section 6	
	4	Peak Surge Forward Current	I _{FSM}	А	100	10ms. Half sine wave, one shot	
	5	Junction Temperature	T_j	°C	-40 to +150		
	6	Storage Temperature	T _{stg}	°C	-40 to +150		

4 Electrical characteristics (Ta=25°C, unless otherwise specified)

No.	Item	Symbol	Unit	Rating	Conditions
1	Forward Voltage Drop	$V_{\rm F}$	v	0.91 max.	I _F =1.5A
2	Reverse Leakage Current	I _R	μΑ	10 max.	V _R =V _{RM}
3	Reverse Leakage Current Under High Temperature	$H \cdot I_R$	μΑ	50 max.	V _R =V _{RM} , T _j =100°C
4	Thermal Resistance	R _{th(j-l)}	°C/W	12 max.	Between Junction and Lead



- 7 Package information
 - 7-1Package type, physical dimensions and material

